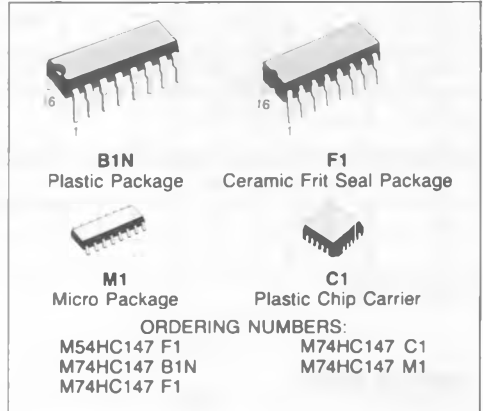


## 10 TO 4 LINE PRIORITY ENCODER

- **HIGH SPEED**  
 $t_{PD} = 16 \text{ ns (TYP.) at } V_{CC} = 5 \text{ V}$
- **LOW POWER DISSIPATION**  
 $I_{CC} = 4 \mu\text{A (MAX.) at } T_A = 25^\circ\text{C}$
- **HIGH NOISE IMMUNITY**  
 $V_{NIH} = V_{NIL} = 28\% V_{CC} \text{ (MIN.)}$
- **OUTPUT DRIVE CAPABILITY**  
 10 LSTTL LOADS
- **SYMMETRICAL OUTPUT IMPEDANCE**  
 $|I_{OH}| = |I_{OL}| = 4 \text{ mA (MIN.)}$
- **BALANCED PROPAGATION DELAYS**  
 $t_{PLH} = t_{PHL}$
- **WIDE OPERATING VOLTAGE RANGE**  
 $V_{CC} \text{ (OPR)} = 2 \text{ V to } 6 \text{ V}$
- **PIN AND FUNCTION COMPATIBLE**  
 WITH 54/74LS147

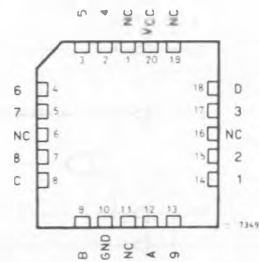
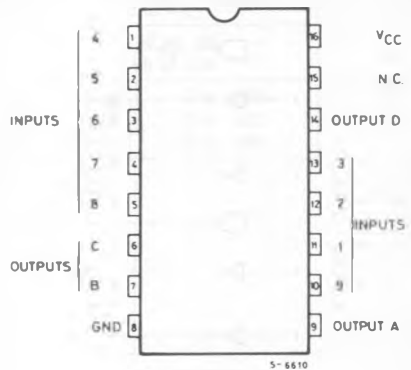


### DESCRIPTION

The M54/74HC147 is a high speed CMOS 10 TO 4 LINE PRIORITY ENCODER fabricated in silicon gate C<sup>2</sup>MOS technology. It has the same high speed performance of LSTTL combined with true CMOS low power consumption.

This device features priority encoding of the inputs to ensure that only the highest order data line is encoded. Nine input lines are encoded to a four line BCD output. The implied decimal zero condition requires no input condition as zero is encoded when all nine data lines are at a high logic level. All data input and outputs are active at the low logic level. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### PIN CONNECTIONS (top view)



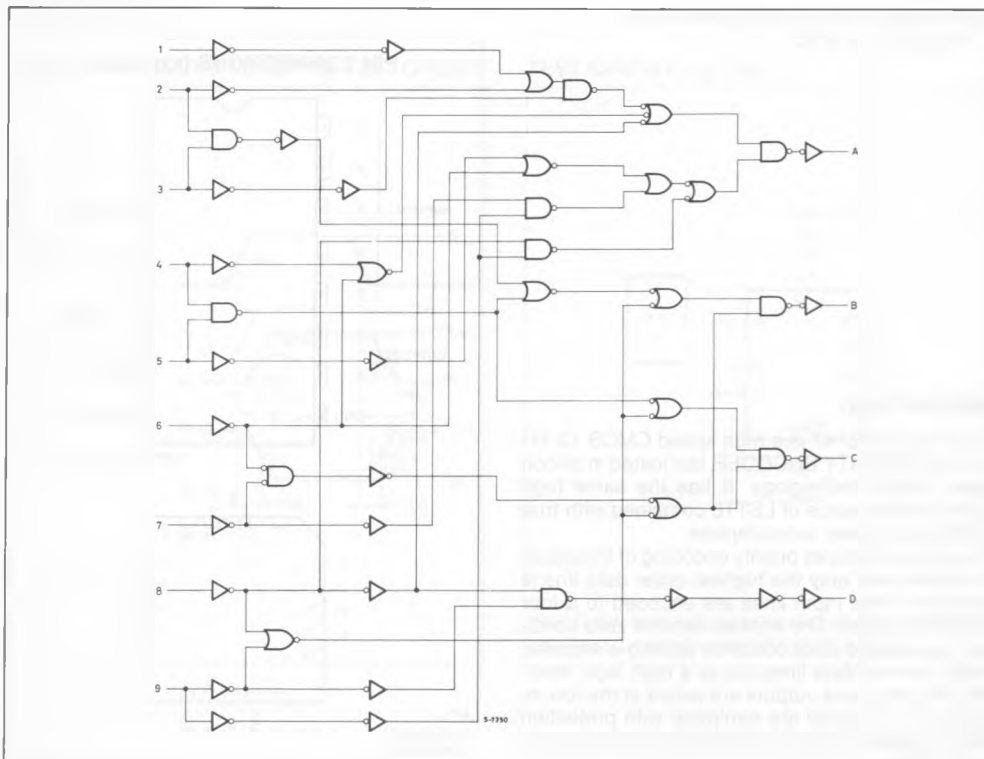
NC =  
 No Internal  
 Connection

## TRUTH TABLE

INPUT									OUTPUT			
1	2	3	4	5	6	7	8	9	D	C	B	A
H	H	H	H	H	H	H	H	H	H	H	H	H
X	X	X	X	X	X	X	X	L	L	H	H	L
X	X	X	X	X	X	X	L	H	L	H	H	H
X	X	X	X	X	X	L	H	H	H	L	L	L
X	X	X	X	X	L	H	H	H	H	L	L	H
X	X	X	X	L	H	H	H	H	H	L	H	L
X	X	X	L	H	H	H	H	H	H	L	H	H
X	X	L	H	H	H	H	H	H	H	H	L	L
X	L	H	H	H	H	H	H	H	H	H	L	H
L	H	H	H	H	H	H	H	H	H	H	H	L

X: DON'T CARE

## LOGIC DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	- 0.5 to 7	V
$V_I$	DC Input Voltage	- 0.5 to $V_{CC} + 0.5$	V
$V_O$	DC Output Voltage	- 0.5 to $V_{CC} + 0.5$	V
$I_{IK}$	DC Input Diode Current	$\pm 20$	mA
$I_{OK}$	DC Output Diode Current	$\pm 20$	mA
$I_O$	DC Output Source Sink Current Per Output Pin	$\pm 25$	mA
$I_{CC}$ or $I_{GND}$	DC $V_{CC}$ or Ground Current	$\pm 50$	mA
$P_D$	Power Dissipation	500 (*)	mW
$T_{stg}$	Storage Temperature	- 65 to 150	$^{\circ}C$

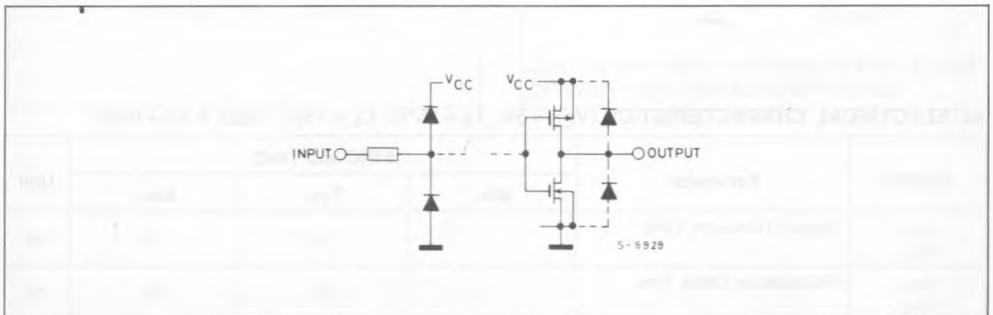
Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

(\*) 500 mW:  $\equiv 65^{\circ}C$  derate to 300 mW by 10 mW/ $^{\circ}C$ :  $65^{\circ}C$  to  $85^{\circ}C$

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply Voltage	2 to 6	V
$V_I$	Input Voltage	0 to $V_{CC}$	V
$V_O$	Output Voltage	0 to $V_{CC}$	V
$T_A$	Operating Temperature 74HC Series 54HC Series	- 40 to 85 - 55 to 125	$^{\circ}C$
$t_r, t_f$	Input Rise and Fall Time	$V_{CC} \begin{cases} 2 \text{ V} & 0 \text{ to } 1000 \\ 4.5 \text{ V} & 0 \text{ to } 500 \\ 6 \text{ V} & 0 \text{ to } 400 \end{cases}$	ns

## INPUT AND OUTPUT EQUIVALENT CIRCUIT



## DC SPECIFICATIONS

Symbol	Parameter	V <sub>CC</sub>	Test Condition	T <sub>A</sub> = 25°C 54HC and 74HC			- 40 to 85°C 74HC		- 55 to 125°C 54HC		Unit	
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.		
				V <sub>IH</sub>	High Level Input Voltage	2.0 4.5 6.0		1.5 3.15 4.2	— — —	— — —		1.5 3.15 4.2
V <sub>IL</sub>	Low Level Input Voltage	2.0 4.5 6.0		— — —	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	— — —	0.5 1.35 1.8	V	
V <sub>OH</sub>	High Level Output Voltage	2.0 4.5 6.0	V <sub>I</sub>	I <sub>O</sub>	1.9	2.0	—	1.9	—	1.9	—	V
			V <sub>IH</sub> or V <sub>IL</sub>	- 20 μA	4.4 5.9	4.5 6.0	— —	4.4 5.9	— —	4.4 5.9	— —	
				- 4.0 mA - 5.2 mA	4.18 5.68	4.31 5.8	— —	4.13 5.63	— —	4.10 5.60	— —	
V <sub>OL</sub>	Low Level Output Voltage	2.0 4.5 6.0	V <sub>IH</sub> or V <sub>IL</sub>	20 μA	— — —	0 0 0	0.1 0.1 0.1	— — —	0.1 0.1 0.1	— — —	0.1 0.1 0.1	V
				4.0 mA 5.2 mA	— —	0.17 0.18	0.26 0.26	— —	0.33 0.33	— —	0.40 0.40	
					— —	— —	— —	— —	— —	— —	— —	
I <sub>I</sub>	Input Leakage Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	±0.1	—	±1	—	±1	μA	
I <sub>CC</sub>	Quiescent Supply Current	6.0	V <sub>I</sub> = V <sub>CC</sub> or GND	—	—	4	—	40	—	80	μA	

AC ELECTRICAL CHARACTERISTICS (V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C, C<sub>L</sub> = 15pF, Input t<sub>r</sub> = t<sub>f</sub> = 6ns)

Symbol	Parameter	54HC and 74HC			Unit
		Min.	Typ.	Max.	
t <sub>TLH</sub> t <sub>THL</sub>	Output Transition Time		4	8	ns
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay Time		16	26	ns

AC ELECTRICAL CHARACTERISTICS ( $C_L = 50\text{pF}$ , Input  $t_r = t_f = 6\text{ns}$ )

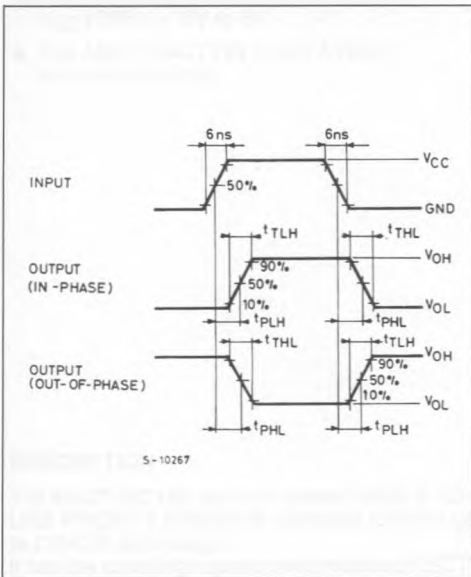
Symbol	Parameter	$V_{CC}$	Test Condition	$T_A = 25^\circ\text{C}$ 54HC and 74HC			$-40$ to $85^\circ\text{C}$ 74HC		$-55$ to $125^\circ\text{C}$ 54HC		Unit
				Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
$t_{TLH}$ $T_{THL}$	Output Transition Time Output	2.0 4.5 6.0		— — —	30 8 7	75 15 13	— — —	95 19 16	— — —	110 22 19	ns
$t_{PLH}$ $t_{PHL}$	Propagation Delay Time	2.0 4.5 6.0		— — —	76 19 16	150 30 26	— — —	190 38 33	— — —	225 45 38	ns
$C_{IN}$	Input Capacitance			—	5	10	—	10	—	—	pF
$C_{PD} (*)$	Power Dissipation Capacitance			—	37	—	—	—	—	—	pF

Note (\*)  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit)

Average operating current can be obtained by the following equation.

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## SWITCHING CHARACTERISTICS TEST CIRCUIT

TEST CIRCUIT  $I_{CC}$  (Opr.)